LM6142 Dual and LM6144 Quad High Speed/Low Power 17 MHz Rail-to-Rail Input-Output Operational Amplifiers

General Description

Using patent pending new circuit topologies, the LM6142/44 provides new levels of performance in applications where low voltage supplies or power limitations previously made compromise necessary. Operating on supplies of 1.8V to over 24V, the LM6142/44 is an excellent choice for battery operated systems, portable instrumentation and others.

The greater than rail-to-rail input voltage range eliminates concern over exceeding the common-mode voltage range. The rail-to-rail output swing provides the maximum possible dynamic range at the output. This is particularly important when operating on low supply voltages.

High gain-bandwidth with 650 μ A/Amplifier supply current opens new battery powered applications where previous higher power consumption reduced battery life to unacceptable levels. The ability to drive large capacitive loads without oscillating functionally removes this common problem.

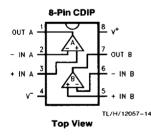
Features At $V_S = 5V$. Typ unless noted.

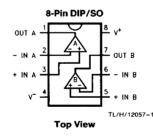
- Rail-to-rail input CMVR -0.25V to 5.25V
- Rail-to-rail output swing 0.005V to 4.995V
- Wide gain-bandwidth: 17 MHz at 50 kHz (typ)
- Slew rate:
 - Small signal, 5V/μs Large signal, 30V/μs
- Low supply current 650 µA/Amplifier
- Wide supply range 1.8V to 24V
- CMRR 107 dB
- Gain 108 dB with R_L = 10k
- PSRR 87 dB

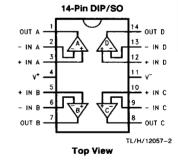
Applications

- Battery operated instrumentation
- Depth sounders/fish finders
- Barcode scanners
- Wireless communications
- Rail-to-rail in-out instrumentation amps

Connection Diagrams







Ordering Information

	Temperature Range	Temperature Range	NSC	
Package	Industrial - 40°C to + 85°C	Military -55°C to + 125°C	Drawing	
8-Pin Molded DIP	LM6142AIN, LM6142BIN		N08E	
8-Pin Small Outline	LM6142AIM, LM6142BIM		M08A	
14-Pin Molded DIP	LM6144AIN, LM6144BIN		N14A	
14-Pin Small Outline	LM6144AIM, LM6144BIM		M14A	
8-Pin CDIP		LM6142AMJ/883	D08C	

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RRD-820M65/Printed in U. S. A.

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

ESD Tolerance (Note 2)
Differential Input Voltage

2500V 15V

150°C

Voltage at Input/Output Pin

 $(V^+) + 0.3V, (V^-) - 0.3V$

Supply Voltage (V $^+$ – V $^-$) 35V Current at Input Pin \pm 10 mA

 Current at Output Pin (Note 3)
 ± 25 mA

 Current at Power Supply Pin
 50 mA

Lead Temperature (soldering, 10 sec) 260°C Storage Temp. Range -65°C to +150°C

Junction Temperature (Note 4)

Operating Ratings (Note 1)

Supply Voltage

Junction Temperature Range LM6142, LM6144 -

-40°C ≤ T_J ≤ +85°C

 $1.8V \leq V^+ \leq 24V$

Thermal Resistance (θ_{JA})

N Package, 8-Pin Molded DIP 115°C/W M Package, 8-Pin Surface Mount 193°C/W N Package, 14-Pin Molded DIP 81°C/W

M Package, 14-Pin Surface Mount 126°C/W

5.0V DC Electrical Characteristics

Unless otherwise specified, all limits guaranteed for $T_J = 25^{\circ}C$, $V^+ = 5.0V$, $V^- = 0V$, $V_{CM} = V_O = V^+/2$ and $R_L > 1$ M Ω to V + /2. **Boldface limits** apply at the temperature extremes.

Symbol	Parameter	Conditions	Typ (Note 5)	LM6144AI LM6142AI Limit (Note 6)	LM6144BI LM6142BI Limit (Note 6)	Units
Vos	Input Offset Voltage		0.3	1.0 2.2	2.5 3.3	mV max
TCV _{OS}	Input Offset Voltage Average Drift		3			μV/°C
IB	Input Bias Current		170	250	300	nA
		0V ≤ V _{CM} ≤ 5V	180	280 526	526	max
los	Input Offset Current		3	30 80	30 80	nA max
R _{IN}	Input Resistance, C _M		126			MΩ
CMRR	Common Mode Rejection Ratio	0V ≤ V _{CM} ≤ 4V	107	84 78	84 78	
		0V ≤ V _{CM} ≤ 5V	82 79	66 64	66 64	dB min
PSRR	Power Supply Rejection Ratio	5V ≤ V + ≤ 24V	87	80 78	80 78	
V _{CM}	Input Common-Mode		-0.25	0	0	v
	Voltage Range		5.25	5.0	5.0	1 °
A _V	Large Signal Voltage Gain	R _L = 10k	270 70	100 33	80 25	V/mV min
v _o	Output Swing	R _L = 100k	0.005	0.01 0.013	0.01 0.013	V max
			4.995	4.98 4.93	4.98 4.93	V min
		R _L = 10k	0.02			V max
			4.97			V min
		R _L = 2k	0.06	0.1 0.133	0.1 0.133	V max
			4.90	4.86 4.80	4.86 4.80	V min

5.0V DC Electrical Characteristics

Unless Otherwise Specified, All Limits Guaranteed for $T_J=25^{\circ}C$, $V^+=5.0V$, $V^-=0V$, $V_{CM}=V_O=V^+/2$ and $R_L>1~M\Omega$ to $V^+/2$. **Boldface limits** apply at the temperature extremes. (Continued)

Symbol	Parameter	Conditions	Typ (Note 5)	LM6144AI LM6142AI Limit (Note 6)	LM6144BI LM6142BI Limit (Note 6)	Units
Isc	Output Short Circuit Current	Sourcing	13	10 4.9	8 4	mA min
	LM6142			35	35	mA max
		Sinking	24	10 5.3	10 5.3	mA min
				35	35	mA max
Isc	Output Short Circuit Current	Sourcing	8	6 3	6 3	mA min
	LM6144			35	35	mA max
		Sinking	22	8 4	8 4	mA min
				35	35	mA max
Is	Supply Current	Per Amplifier	650	800 880	800 880	μA max

5.0V AC Electrical Characteristics

Unless Otherwise Specified, All Limits Guaranteed for $T_J=25^{\circ}C$, $V^+=5.0V$, $V^-=0V$, $V_{CM}=V_O=V^+/2$ and $R_L>1$ M Ω to $V_S/2$. **Boldface limits** apply at the temperature extremes.

Symbol	Parameter	Conditions	Typ (Note 5)	LM6144Al LM6142Al Limit (Note 6)	LM6144BI LM6142BI Limit (Note 6)	Units
SR	Slew Rate	8 V _{p-p} @ V _{CC} 12V R _S > 1 kΩ	25	15 13	13 11	V/μs min
GBW	Gain-Bandwidth Product	f = 50 kHz	17	10 6	10 6	MHz min
φm	Phase Margin		38			Deg
	Amp-to-Amp Isolation		130			dB
e _n	Input-Referred Voltage Noise	f = 1 kHz	16			nV √Hz
in	Input-Referred Current Noise	f = 1 kHz	0.22			pA √Hz
T.H.D.	Total Harmonic Distortion	$f = 10 \text{ kHz}, R_L = 10 \text{ k}\Omega,$	0.003			%

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2.7V DC Electrical Characteristics

Unless Otherwise Specified, All Limits Guaranteed for $T_J=25^{\circ}C$, $V^+=2.7V$, $V^-=0V$, $V_{CM}^-=V_O^-=V^+/2$ and $R_L>1$ M Ω to $V^+/2$. **Boldface** limits apply at the temperature extreme

Symbol	Parameter	Conditions	Typ (Note 5)	LM6144AI LM6142AI Limit (Note 6)	LM6144BI LM6142BI Limit (Note 6)	Units
Vos	Input Offset Voltage		0.4	1.8 4.3	2.5 4.3	mV max
IB	Input Bias Current		150	250 526	300 526	nA max
los	Input Offset Current		4	30 80	30 80	nA max
RIN	Input Resistance		128			МΩ
CMRR	Common Mode	0V ≤ V _{CM} ≤ 1.8V	90			
	Rejection Ratio	0V ≤ V _{CM} ≤ 2.7V	76			d₿
PSRR	Power Supply Rejection Ratio	3V ≤ V + ≤ 5V	79			min
V _{CM}	Input Common-Mode		-0.25	0	0	V min
	Voltage Range		2.95	2.7	2.7	V max
A _V	Large Signal Voltage Gain	R _L = 10k	55			V/mV min
V _O	Output Swing	$R_L = 10 \text{ k}\Omega$	0.019	0.08 0.112	0.08 0.112	V max
			2.67	2.66 2.25	2.66 2.25	V min
Is	Supply Current	Per Amplifier	510	800 880	800 880	μA max

2.7V AC Electrical Characteristics

Unless Otherwise Specified, All Limits Guaranteed for $T_J=25^{\circ}C$, $V^+=2.7V$, $V^-=0V$, $V_{CM}^-=V_O=V^+/2$ and $R_L>1$ M Ω to $V^+/2$. **Boldface** limits apply at the temperature extreme

Symbol	Parameter	Conditions	Typ (Note 5)	LM6144AI LM6142AI Limit (Note 6)	LM6144BI LM6142BI Limit (Note 6)	Units
GBW	Gain-Bandwidth Product	f = 50 kHz	9			MHz
φm	Phase Margin		36			Deg
G _m	Gain Margin		6			dB

24V Electrical Characteristics

Unless Otherwise Specified, All Limits Guaranteed for $T_J=25^{\circ}C$, $V^+=24V$, $V^-=0V$, $V_{CM}=V_O=V^+/2$ and $R_L>1~M\Omega$ to $V_S/2$. **Boldface** limits apply at the temperature extreme

Symbol	Parameter	Conditions	Typ (Note 5)	LM6144Ai LM6142AI Limit (Note 6)	LM6144BI LM6142BI Limit (Note 6)	Units
Vos	Input Offset Voltage		1.3	2 4.8	3.8 4.8	mV max
IB	Input Bias Current		174			nA max
los	Input Offset Current		5			nA max
R _{IN}	Input Resistance		288			МΩ
CMRR	Common Mode Rejection Ratio	0V ≤ V _{CM} ≤ 23V	114			
		0V ≤ V _{CM} ≤ 24V	100			d₿
PSRR	Power Supply Rejection Ratio	0V ≤ V _{CM} ≤ 24V	87			min
V _{CM}	Input Common-Mode		-0.25	0	0	V min
	Voltage Range		24.25	24	24	V max
A _V	Large Signal Voltage Gain	R _L = 10k	500			V/mV min
V _O	Output Swing	$R_L = 10 \text{ k}\Omega$	0.07	0.15 0.185	0.15 0.185	V max
			23.85	23.81 23.62	23.81 23.62	V min
Is	Supply Current	Per Amplifier	750	1100 1150	1100 1150	μA max
GBW	Gain-Bandwidth Product	f = 50 kHz	18			MHz

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not guaranteed. For guaranteed specifications and the test conditions, see the Electrical Characteristics.

Note 2: Human body model, 1.5 kt) in series with 100 pF.

Note 3: Applies to both single-supply and split-supply operation. Continuous short circuit operation at elevated ambient temperature can result in exceeding the maximum allowed junction temperature of 150°C.

Note 4: The maximum power dissipation is a function of $T_{J(max)}$. θ_{JA} , and T_A . The maximum allowable power dissipation at any ambient temperature is $P_D = (T_{J(max)} - T_A)/\theta_{JA}$. All numbers apply for packages soldered directly into a PC board.

Note 5: Typical values represent the most likely parametric norm.

Note 5: All limits are guaranteed by testing or statistical analysis.

Note 7: For guaranteed military specifications see military datasheet MNLM6142AM-X.

Typical Performance Characteristics $T_A=25^{\circ}C,\,R_L=10\;k\Omega$ Unless Otherwise Specified **Bias Current vs Supply Current vs** Offset Voltage vs **Supply Voltage** Supply Voltage Supply Voltage 3.0 SUPPLY CURRENT (MA) PER AMPLIFIER 2.7 -50 2.4 0.8 (۳ +85°C -100 (nA) 2.1 VOLTAGE CURRENT 18 -150 1.5 -200 1.2 OFFSET 0.9 -250 0.6 0.2 -300 0.3 0.0 0.0 10 15 20 25 30 16 12 16 20 24 28 0 SUPPLY VOLTAGE (V) SUPPLY VOLTAGE (V) SUPPLY VOLTAGE (V) Offset Voltage vs V_{CM} Offset Voltage vs V_{CM} Offset Voltage vs V_{CM} 1.0 1.0 1.0 0.8 0.8 0.6 0.6 0.5 (m) OFFSET VOLTAGE (mV) 0.4 0.4 VOLTAGE 0.2 0.2 <u>}</u> 0.0 0 š -0.2 -0.2 OFFSET -0.4 -0.4 -0.5 -0.6 -0.6 -0.8 -0.8 -1.0 -1.0 -6 -5 -4 -3 -2 -1 0 1 2 3 4 5 6 -2 -1.5 -1 -0.5 0 0.5 1.5 -3 0 COMMON MODE VOLTAGE (V) COMMON MODE VOLTAGE (V) COMMON MODE VOLTAGE (V) Bias Current vs V_{CM} Bias Current vs V_{CM} Bias Current vs V_{CM} 500 500 = +2.5V 400 400 400 300 300 300 3 200 BIAS CURRENT (nA) 200 CURRENT (nA) 200 100 100 100 CURRENT 0 ก +8500 +8500 -100 -100 -100 -200 -200 -200 +25°C -300 -300 -300 -40°C -400 -400 -400 -500 -500 0 -1.5 -1 -0.5 O 0.5 -3 -2 COMMON MODE VOLTAGE (V) COMMON MODE VOLTAGE (V) COMMON MODE VOLTAGE (V) **Open-Loop Transfer Open-Loop Transfer Open-Loop Transfer** Function Function **Function** 250 100 100 = 10V 80 80 60 60 150 VOLTAGE (µV) VOLTAGE (µV) INPUT VOLTAGE (µV) 40 100 40 20 50 20 1004 100k 0 0 101 -20 101 -50 -20 POI -40 -100 2k -150 -60 -60 -200 -80 -100 -100 -250 2.5 0 0.5 1 1.5 2 2.5 3 3.5 4 4.5 5 4 5 6 7 8 2 1.5 OUTPUT VOLTAGE (V) OUTPUT VOLTAGE (V) OUTPUT VOLTAGE (V) TL/H/12057-3

Typical Performance Characteristics $T_A = 25^{\circ}C$, $R_1 = 10 \text{ k}\Omega$ Unless Otherwise Specified (Continued) Output Voltage vs **Output Voltage vs Output Voltage vs Source Current Source Current Source Current** SOURCE CURRENT (mA) SOURCE CURRENT (mA) SOURCE CURRENT (mA) 0.01 0.01 0.01 10 10000 10 10000 10 100 1000 OUTPUT SWING FROM V+ (mV) OUTPUT SWING FROM V+ (mV) OUTPUT SWING FROM V+ (mV) Output Voltage vs Output Voltage vs **Output Voltage vs** Sink Current Sink Current Sink Current 100 100 100 +850€ v_s = 5v OUTPUT SINK CURRENT (MA) SINK CURRENT (mA) OUTPUT SINK CURRENT (mA) 10 10 10 +2500 0. 0. OUTPUT 5 0.0 0.01 0.01 0.001 0.001 0.001 0.1 100 1000 0.1 100 1000 100 1000 10000 10 OUTPUT SWING FROM V- (mV) OUTPUT SWING FROM V- (mV) OUTPUT SWING FROM V- (mV) TL/H/12057-4 **Distortion + Noise** Gain and Phase vs Load vs Frequency Gain and Phase vs Load 120 120 V_S = 24V V_S = 5V -68 150 100 150 100 -70 120 80 120 80 -72 (gp) (BB) 60 90 60 -74 DISTORTION -76 40 40 = 10k | 100 pf 100 p -78 20 20 -80 0 -82 -20 8k 6k 10k 40k B0k 60k 100k 10 100 10k 1006 101 10 100 16 101 1006 114 104 FREQUENCY (Hz) FREQUENCY (Hz) FREQUENCY (Hz) **GBW** vs Supply 25.00 20.00 GAIN-BANDWIDTH (MHZ) 15.00 10.00 5.00

0.00

SUPPLY VOLTAGE (V)

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Typical Performance Characteristics T_A = 25°C, R_L = 10 kΩ Unless Otherwise Specified (Continued) Open Loop Gain vs Open Loop Gain vs Open Loop Gain vs Load, 3V Supply Load, 5V Supply Load, 24V Supply 120 120 120 100 100 100 (BB) 9 OPEN LOOP GAIN (48) 80 80 PEN LOOP GAIN GAIN 104 60 60 60 R 100 P 40 40 NEN 20 20 20 ٥ 0 -20 -20 10 100 10k 100k 1 M 10M 10 100 100k 1 M 10M 10k 1 M 1 DM FREQUENCY (Hz) FREQUENCY (Hz) FREQUENCY (Hz) Unity Gain Freq vs VS **CMRR** vs Frequency Crosstalk vs Frequency 25 120 150 V_S = 10V 115 140 20 110 R₁ = ≥ 10k FREQUENCY (MHz) ISOLATION (dB) 130 105 15 (BB) 100 120 10 95 110 90 5 100 R. D 10 15 20 25 10 100 1k 10k 100k 0.1 100 SUPPLY VOLTAGE (V) FREQUENCY (Hz) FREQUENCY (kHz) **PSRR vs Frequency** Noise Voltage vs Frequency Noise Current vs Frequency 1000 800 600 **40**0 100.0 90.0 NOISE CURRENT (pA/VHz) NOISE VOLTAGE (nV/VHZ) 70.0 200 60.0 PSRR (dB) 100 80 60 50.0 NEG PSI 0.8 40.0 30.0 40 20.0 POS PSE 20 0.2 10.0 0.0 100 0.01 0.1 10 10k 100k 1 M 10M 10 100 1000 0.1 100 1000 10000 FREQUENCY (Hz) FREQUENCY (Hz) FREQUENCY (Hz) TL/H/12057-5 **NE vs R Source** 20 16 NOISE FIGURE (4B) 12 10 8 2 100 10k 100k 10M R_{SOURCE} (Ω) TL/H/12057-12

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LM6142/44 Application Ideas

The LM6142 brings a new level of ease of use to opamp system design.

With greater than rail-to-rail input voltage range concern over exceeding the common-mode voltage range is eliminated.

Rail-to-rail output swing provides the maximum possible dynamic range at the output. This is particularly important when operating on low supply voltages.

The high gain-bandwidth with low supply current opens new battery powered applications, where high power consumption, previously reduced battery life to unacceptable levels.

To take advantage of these features, some ideas should be kept in mind.

ENHANCED SLEW RATE

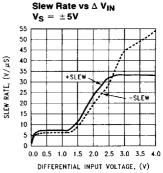
Unlike most bipolar opamps, the unique phase reversal prevention/speed-up circuit in the input stage causes the slew rate to be very much a function of the input signal amplitude. Figure 1 shows how excess input signal, is routed around the input collector-base junctions, directly to the current mirrors

The LM6142/44 input stage converts the input voltage change to a current change. This current change drives the current mirrors through the collectors of Q1-Q2, Q3-Q4 when the input levels are normal.

If the input signal exceeds the slew rate of the input stage, the differential input voltage rises above two diode drops. This excess signal bypasses the normal input transistors, (Q1-Q4), and is routed in correct phase through the two additional transistors, (Q5, Q6), directly into the current mirrors.

This rerouting of excess signal allows the slew-rate to increase by a factor of 10 to 1 or more. (See Figure 2.)

As the overdrive increases, the opamp reacts better than a conventional opamp. Large fast pulses will raise the slew-rate to around 30V to $60V/\mu s$.



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FIGURE 2

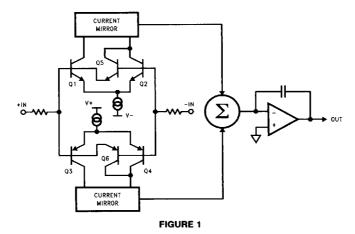
This effect is most noticeable at higher supply voltages and lower gains where incoming signals are likely to be large.

This new input circuit also eliminates the phase reversal seen in many opamps when they are overdriven.

This speed-up action adds stability to the system when driving large capacitive loads.

DRIVING CAPACITIVE LOADS

Capacitive loads decrease the phase margin of all opamps. This is caused by the output resistance of the amplifier and the load capacitance forming an R-C phase lag network. This can lead to overshoot, ringing and oscillation. Slew rate limiting can also cause additional lag. Most opamps with a fixed maximum slew-rate will lag further and further behind when driving capacitive loads even though the differential input voltage raises. With the LM6142, the lag causes the slew rate to raise. The increased slew-rate keeps the output following the input much better. This effectively reduces phase lag. After the output has caught up with the input, the differential input voltage drops down and the amplifier settles rapidly.



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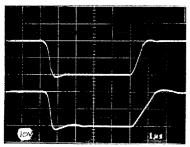
LM6142/44 Application Ideas

(Continued)

These features allow the LM6142 to drive capacitive loads as large as 1000 pF at unity gain and not oscillate. The scope photos (Figure 3a and 3b) above show the LM6142 driving a 1000 pF load. In Figure 3a, the upper trace is with no capacitive load and the lower trace is with a 1000 pF load. Here we are operating on $\pm 12V$ supplies with a 20 Vp-p pulse. Excellent response is obtained with a Cf of 10 pF. In Figure 3b, the supplies have been reduced to ±2.5V, the pulse is 4 Vp-p and Cf is 39 pF. The best value for the compensation capacitor is best established after the board layout is finished because the value is dependent on board stray capacity, the value of the feedback resistor, the closed loop gain and, to some extent, the supply voltage.

Another effect that is common to all opamps is the phase shift caused by the feedback resistor and the input capacitance. This phase shift also reduces phase margin. This effect is taken care of at the same time as the effect of the capacitive load when the capacitor is placed across the feedback resistor.

The circuit shown in Figure 4 was used for these scope photos.



TL/H/12057-8

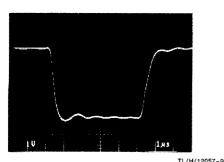


FIGURE 3a

FIGURE 3b

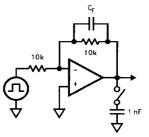


FIGURE 4

TL/H/12057-10

Typical Applications

FISH FINDER/ DEPTH SOUNDER.

The LM6142/44 is an excellent choice for battery operated fish finders. The low supply current, high gain-bandwidth and full rail to rail output swing of the LM6142 provides an ideal combination for use in this and similar applications.

ANALOG TO DIGITAL CONVERTER BUFFER

The high capacitive load driving ability, rail-to-rail input and output range with the excellent CMR of 82 dB, make the LM6142/44 a good choice for buffering the inputs of A to D converters

3 OPAMP INSTRUMENTATION AMP WITH RAIL-TO-**RAIL INPUT AND OUTPUT**

Using the LM6144, a 3 opamp instrumentation amplifier with rail-to-rail inputs and rail to rail output can be made. These features make these instrumentation amplifiers ideal for single supply systems.

Some manufacturers use a precision voltage divider array of 5 resistors to divide the common-mode voltage to get an input range of rail-to-rail or greater. The problem with this method is that it also divides the signal, so to even get unity gain, the amplifier must be run at high closed loop gains. This raises the noise and drift by the internal gain factor and lowers the input impedance. Any mismatch in these precision resistors reduces the CMR as well. Using the LM6144, all of these problems are eliminated.

In this example, amplifiers A and B act as buffers to the differential stage (Figure 5). These buffers assure that the input impedance is over 100 M Ω and they eliminate the requirement for precision matched resistors in the input stage. They also assure that the difference amp is driven from a voltage source. This is necessary to maintain the CMR set by the matching of R1-R2 with R3-R4.

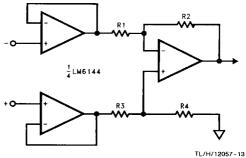
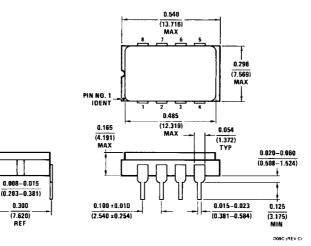


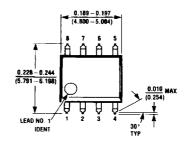
FIGURE 5

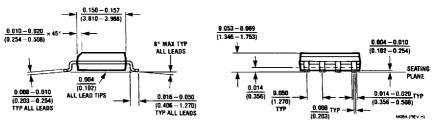
The gain is set by the ratio of R2/R1 and R3 should equal past the supplies so the combined common mode voltage R1 and R4 equal R2. Making R4 slightly smaller than R2 plus the signal should not be greater than the supplies or and adding a trim pot equal to twice the difference between limiting will occur. R2 and R4 will allow the CMR to be adjusted for optimum. SPICE MACROMODEL With both rail to rail input and output ranges, the inputs and A SPICE macromodel of this and many other National Semioutputs are only limited by the supply voltages. Remember conductor opamps is available at no charge from the NSC that even with rail-to-rail output, the output can not swing Customer Response Group at 800-272-9959.

Physical Dimensions inches (millimeters)



8-Pin Ceramic Sidebrazed Dual-In-Line Package Order Number LM6142AMJ/883 NS Package Number D08C

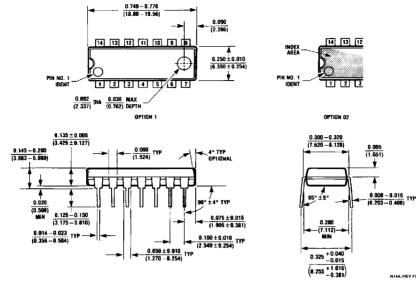




8-Pin Small Outline Package Order Number LM6142AIM or LM6142BIM NS Package Number M08A

Physical Dimensions inches (millimeters) (Continued) 0.228 - 0.244 LEAD NO. 1 0.053 - 0.069 (1.345 - 1.753) 0.010 - 0.020 (0.254 - 0.508) 8° MAX TYP 0.050 (1.270) TYP 0.014 - 0.020 TYP (D.203 - D.254) TYP ALL LEADS (0.406 - 1.270) TYP ALL LEADS (0.102) ALL LEAD TOPS 14-Pin Small Outline Package Order Number LM6144AIM or LM6144BIM NS Package Number M14A 0.373 - 0.400 (9.474 - 10.16)(2.286)7 6 5 0.092 0.032 ± 0.005 (2.337) (0.813 ± 0.127) 0.250 ± 0.005 PIN NO. 1 IDENT (6.35 ± 0.127) PIN NO. 1 IDENT OPTION 1 1 0.280 0.040 0.030 MAX OPTION 2 (7.112)(1.016) 0.039 0.145 - 0.200(0.762)0.300 - 0.320(0.991)(3.683 - 5.080)(7.62 - 8.128) 0.130 ± 0.005 (3.302 ± 0.127) 0.125 - 0.140 95° ± 5 (3.175 - 3.556)0.065 (1.651) 0.009 - 0.015(3.175)(0.229 - 0.381) 0.018 ± 0.003 0.325 +0.040 -0.015 (0.457±8.076) 0.100 ± 6.010 $8.255 + 1.016 \\ -0.381$ (2.540 ± 0.254) 0.045 ± 0.015 (1.143 ± 0.381) 0.060 (1.524) NOSE (REV F) 8-Pin Molded Dual-In-Line Package Order Number LM6142AIN or LM6142BIN NS Package Number N08E

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14-Pin Molded Dual-In-Line Package Order Number LM6144AIN or LM6144BIN NS Package Number N14A

LIFE SUPPORT POLICY

NATIONAL'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF NATIONAL SEMICONDUCTOR CORPORATION. As used herein:

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- 2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.



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